NSN 5961-01-041-1555

Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-041-1555 **Inclosure Material:** Ceramic or glass or metal or plastic **Overall Length:** Between 0.185 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.100 inches and 0.107 inches **Function For Which Designed:** Zener diode **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 regulator voltage **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 25.00 milliamperes repetitive peak forward current and 5.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release5009 professional/industrial association standard Shelf Life: N/a **Unit Of Measure: Demilitarization:** No